

## Gen 4 Silicon Carbide Schottky Diode

### **Description**

This is the 4th generation of high voltage, high performance Z-Rec<sup>®</sup> silicon carbide Schottky diode in a packageless bare die format to be implemented into any custom module design. The lower forward voltage, smaller reverse leakage current, zero reverse recovery, and high thermal conductivity make this Schottky diode ideal for high frequency switching applications including highs solar inverters and motor drives. This Schottky diode can be used in conjunction with either IGBT or MOSFET as an anti-parallel diode, or as a rectifier.



Package Type: Bare Die PN's: CPW4-1200-S005B

#### **Features**

- 1200V Schottky Rectifier
- Zero Reverse Recovery
- Zero Forward Recovery
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V<sub>F</sub>

### **Applications**

- Solar Inverters
- Motor Drives
- EV Chargers
- UPS
- Industrial Power Supplies

#### **Absolute Maximum Ratings**

Stress beyond those listed under absolute maximum ratings may damage the device.

Parameter	Symbol		Rating	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$		1200	V
Continuous Forward Current	I <sub>F</sub>	T <sub>c</sub> = 175°C	5	А
Repetitive Peak Forward Surge Current, assumes t <sub>p</sub> = 10ms, Half Sine Wave Pulse	I <sub>FRM</sub>	$T_c = 25^{\circ}C$ $T_c = 110^{\circ}C$	26 18	А
Non-Repetitive Forward Surge Current, assumes t <sub>p</sub> = 10ms, Half Sine Wave Pulse	I <sub>FSM</sub>	$T_c = 25^{\circ}C$ $T_c = 110^{\circ}C$	46 36	A
Virtual Junction and Storage Temperature	T <sub>VJ</sub> , T <sub>stg</sub>		-55 to +175	°C
Maximum Processing Temperature, in non-reactive ambient	T <sub>proc</sub>		325	°C

Note: All above notation to  $T_c$  specifies case temperature from die packaged in TO-247, with Rth(j-c) < 1.85°C/W

# Electrical Characteristics (T<sub>VJ</sub> = 25°C)

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions
Forward Valtage	vard Voltage $ V_{\rm f} = \begin{array}{c cccc} 1.4 & 1.8 & \\ \hline 1.9 & 3 & \end{array} $	W	I <sub>F</sub> = 5 A		
Forward voltage		1 -	1.9	3	V
David Comment	I <sub>R</sub>	20	150		V <sub>R</sub> = 1200 V
Reverse Current		IR	40	300	μΑ
Total Capacitive Charge	Qc	27		nC	V <sub>R</sub> = 800 V, I <sub>F</sub> = 5 A, di/dt = 200 A/μs
Total Capacitance	С	390		pF	V <sub>R</sub> = 0 V, f = 1Mhz
		27			V <sub>R</sub> = 400 V, f = 1Mhz
		20			V <sub>R</sub> = 800 V, f = 1Mhz

### **Thermal Characteristics**

Parameter	Symbol	Typical	Unit
Thermal Resistance from Junction to Case <sup>1</sup>	$R_{th(j-c)}$	1.85	°C/W

Note:

<sup>&</sup>lt;sup>1</sup>Tested in TO-247 Package

#### **Typical Performance**

All the graphs are based on a die placed in a TO-247 package.

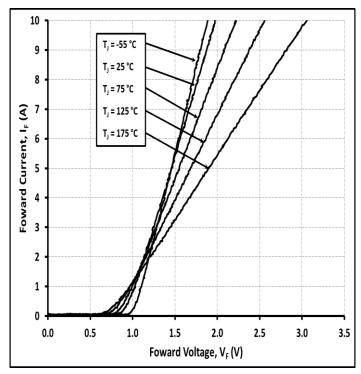


Figure 1.

**Typical Forward Characteristics** 

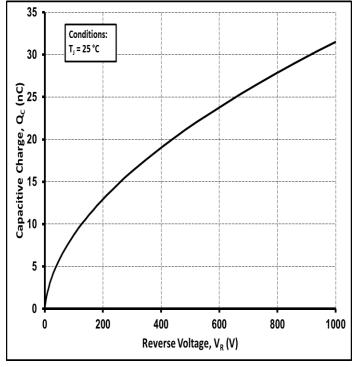


Figure 3.

Typical Capacitance vs Reverse Voltage

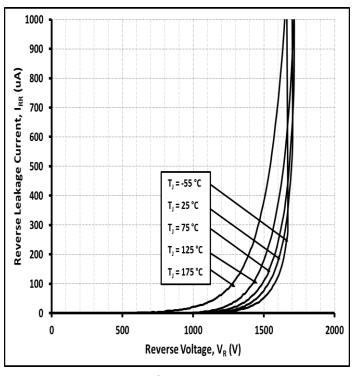


Figure 2.

**Typical Reverse Characteristics** 

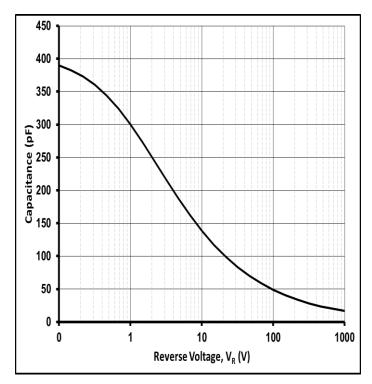
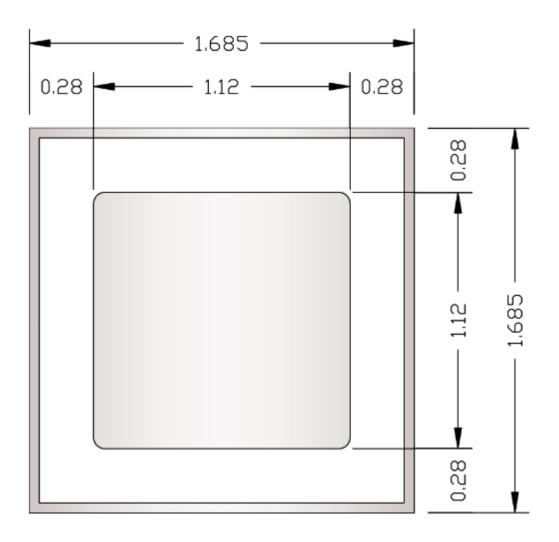


Figure 4.

Typical Recovery Charge vs Reverse Voltage

### **Product Dimensions CPW4-1200-S005B**



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Parameter	Typical	Units
Die Size (L x W)	1.69 x 1.69	mm
Anode Pad Opening	1.12 x 1.12	mm
Die Thickness¹	377 ± 10%	μm
Topside Anode Metalization (Al)	4	μm
Backside Cathode Metalization (Ni/Ag)	1.4	μm
Frontside Passivation (polymide)	Polyimide	

<sup>&</sup>lt;sup>1</sup>SiC Thickness

The information in this document is subject to change without notice.

# **Product Ordering Information**

Order Number	Description	Package
CPW4-1200-S005B-FU6	SiC Diode G4 IND 1200V/5A FULL MLT	Bare Die Product

### **Revision History**

The information in this document is subject to change without notice.

Revision History	Date of Change	Brief Summary	
3		Initial Release	
4	9/30/2023	Template updated	

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